

DATA SHEET

MR Sensor

MRSS31U

Micro power Built-in IC ultra-minimum MR sensor

FEATURES

1.Dimension (Unit:mm) *Micro power (15µW(typ):Vcc=3V) and High-sensitivity(2mT(typ)) (suited for battery-operation)

*Ultra-small size

MR(Magneto-resistance)sensor

- * Volume and mounting area are 50% smaller than MRSS22L.
- * Height is about 4mm lower than MRSS22L.

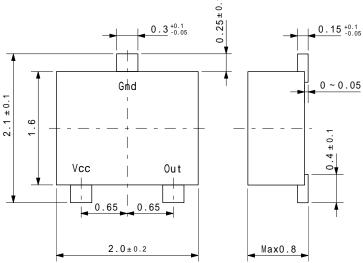
*Operating in one way magnetic field

*Operating with independent pole

(easily manufacture)

*Superior Temperature stability

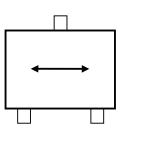
*Lead free goods

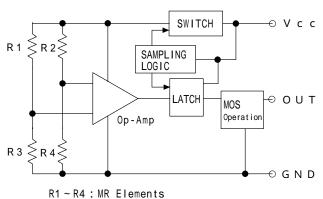


2.Fundamental Operation

2-1.Direction of Magnetic Field

2-2.Circuit Block





	Operating require Condition	Output Voltage					
When power switch is ON	H = 0 mT(Magnetic Flux Density) [0 A/m (Magnetic Field Strength)]	Hi-level					
When magnetic field is applied	$H \geq 2.0(Typ)mT(Magnetic Flux Density)$ $[1.6kA/m (Magnetic Field Strength)]$	Lo-level					
When magnetic field is applied	$H \leq 0.5 \text{ mT} (\text{Magnetic Flux Density})$ $[0.4 \text{kA/m}(\text{Magnetic Field Strength})]$	Hi-level					

2-3.Performance Characteristics (25+3°C)



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3.Performance

3-1. Operating Conditions Recommended

Item	Output	Condition	Min	Std	Max	Unit
Supply Voltage	-	-	2.5	3.0	3.7	V
Supply Current	-	Vcc=3V	-	5	-	μA
Ambient Temperature	-	-	-20	25	80	°C
	VOH	Vcc=3V Iout=2mA	2.7	-	-	V
Output Voltage	VOL	VCC=3V Iout=-2mA	-	-	0.3	V
Operating Magnetic Field	Hi-level output Hon		-	2.0 (1.6)	2.5 (2.0)	mT ^{(*1}
	Lo-level output Hoff		0.5 (0.4)	-	-	(kA/m) (*2

^{*1)} 1 [mT](SI) = 10 [G] (CGS)

 $^{*2)}$ () = [kA/m](SI)

3-2. Absolute Maximum Ratings

(Ta = $25\pm3^{\circ}$ C unless otherwise specified)

Item	Condition	Specifications	Unit
Supply Voltage	-	5.0	v
Storage Temperature	-	-40 ~ +125	°C

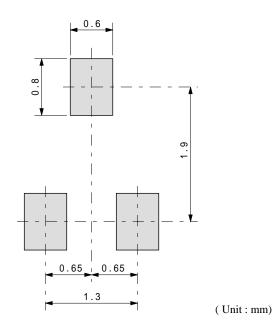
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4. Recommended Mount Pad



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